

PWM Low Supply Current Step-up DC/DC Converter

NO.EA-314-240417

OUTLINE

The R1208x is a low supply current CMOS-based PWM control step-up DC/DC converter. Internally, a single converter consists of an NMOS FET, an oscillator, a PWM comparator, a voltage reference unit, an error amplifier, a current limit circuit, an under voltage lockout circuit (UVLO), an over-voltage protection circuit (OVP), a thermal shutdown protection circuit and current drivers for four white LED channels.

By simply using an inductor, a resistor, capacitors and a diode, white LEDs can be driven with constant current and high efficiency. The LED current can be determined by the value of current setting resistor. The brightness of the LEDs can be adjusted quickly by applying a PWM signal (200 Hz to 300 kHz) to the CE pin.

Protection circuits included in the R1208x are a current limit circuit which limits the L_x peak current, an UVLO circuit which prevents the malfunction of the device at low input voltage, an OVP circuit which monitors the excess output voltage and a thermal shutdown protection circuit which detects the overheating of the device and stops the operation to protect the device from damage.

The R1208x is offered in 12-pin DFN(PL)2730-12 package.

FEATURES

- Input Voltage Range 2.7 V to 22 V
- Supply Current Typ. 600 μ A
- Standby Current Typ. 1.5 μ A
- L_x Current Limit Typ. 2 A
- Overvoltage Protection (OVP)..... Typ. 23 V / 33 V / 43.5 V
- Oscillator Frequency..... Typ. 750 kHz / 450 kHz
- Maximum Duty Cycle..... 95% (750 kHz) / 97% (450 kHz)
- Nch MOSFET ON Resistance..... Typ. 0.28 Ω
- Undervoltage Lockout (UVLO)..... Typ. 2.4 V
- Thermal Shutdown Typ. 150°C
- LED Dimming Control..... By sending a PWM signal (200 Hz to 300 kHz) to the CE pin
- Package DFN(PL)2730-12

APPLICATIONS

- LED backlight driver for LCD displays for portable equipment
- LED backlight driver for LCD displays for Tablets and Note PCs.

SELECTION GUIDE

The OVP threshold voltage and the oscillator frequency are user-selectable options.

Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1208Kx12*-TR	DFN(PL)2730-12	5,000 pcs	Yes	Yes

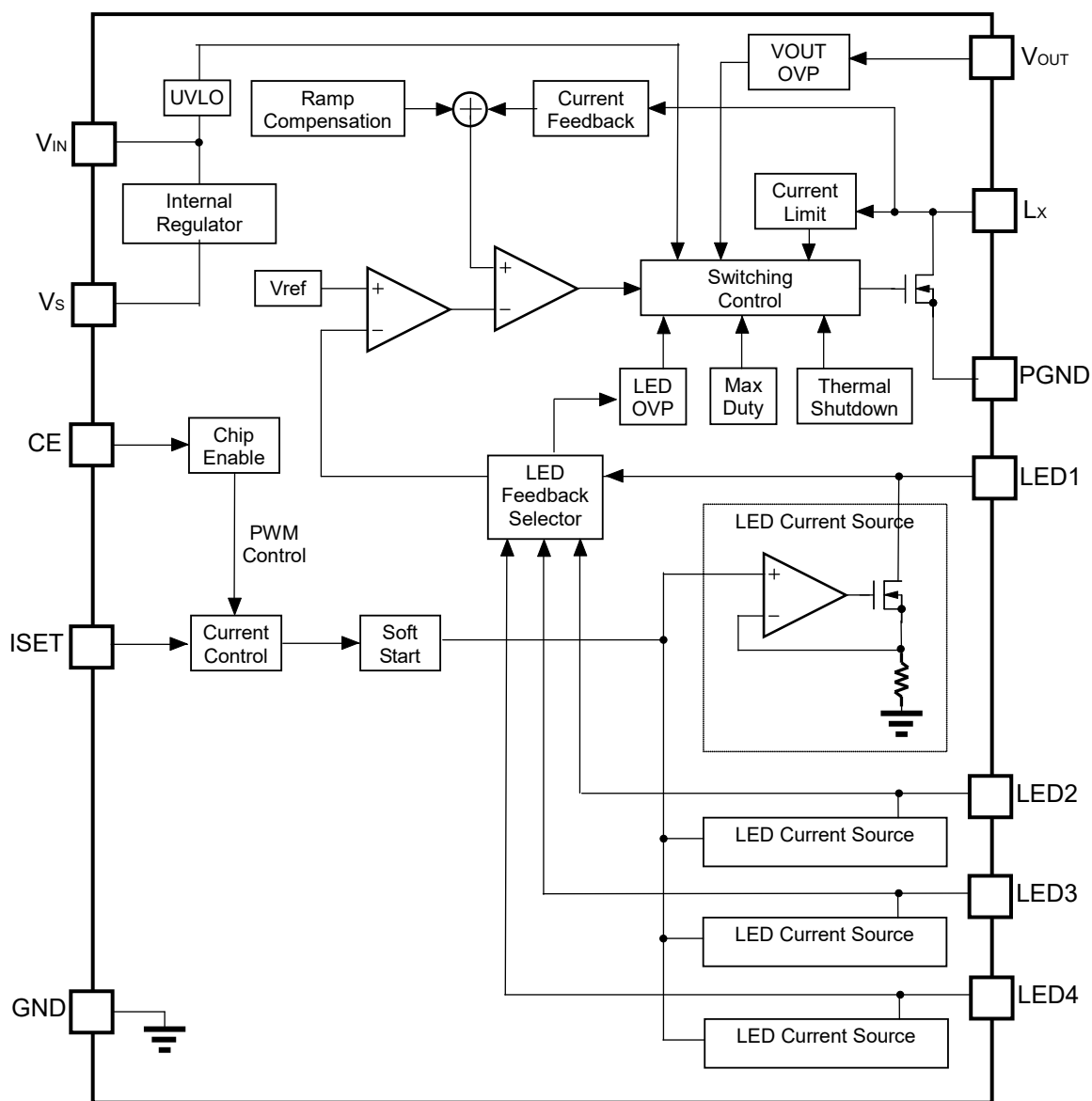
x: Specify the OVP threshold voltage.

- (1) 23 V
- (2) 33 V
- (3) 43.5 V

*: Specify the oscillator frequency.

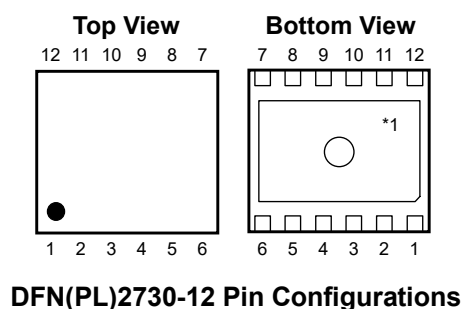
- (A) 750 kHz
- (B) 450 kHz

BLOCK DIAGRAMS



R1208x Block Diagram

PIN DESCRIPTION



DFN(PL)2730-1 Pin Description

Pin No.	Symbol	Description
1	V_{IN}	Power Input Pin
2	LED1	LED1 pin
3	ISET	LED Current Control Pin
4	V_S	Power Input Pin ($V_{IN} < 5\text{ V}$), Internal Regulator Pin ($V_{IN} > 5\text{ V}$)
5	CE	Chip Enable Pin (Active-high)
6	PGND	Power GND Pin
7	L_X	Switching Pin
8	V_{OUT}	Output Pin
9	GND ^{*1}	Analog GND Pin
10	LED4	LED 4 Pin
11	LED3	LED 3 Pin
12	LED2	LED 2 Pin

^{*1} The exposed tab is substrate level (GND). It is recommended that the exposed tab be connected to the ground plane on the board or otherwise be left floating.

ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings

(GND / PGND = 0 V)

Symbol	Item	Rating	Unit
V_{IN}	V_{IN} Pin Voltage	-0.3 to 24	V
V_S	V_S Pin Voltage	-0.3 to 6.5	V
V_{CE}	CE Pin Voltage	-0.3 to 6.5	V
V_{ISET}	I_{SET} Pin Voltage	-0.3 to 6.5	V
V_{OUT}	V_{OUT} Pin Voltage	-0.3 to 48	V
V_{LX}	L_x Pin Voltage	-0.3 to 48	V
V_{LED}	LED1, LED2, LED3, LED4 Pin Voltage	-0.3 to 24	V
I_{LX}	L_x Pin Current	2500	mA
P_D	Power Dissipation* ¹ (JEDEC STD. 51-7 Test Land Pattern)	3100	mW
T_j	Junction Temperature Range	-40 to 125	°C
T_{stg}	Storage Temperature Range	-55 to 125	°C

*¹ Refer to *POWER DISSIPATION* for detailed information.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	2.7 to 22	V
T_a	Operating Temperature Range	-40 to 85	°C

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such ratings by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

The specifications surrounded by are over $-40^{\circ}\text{C} \leq T_a \leq 85^{\circ}\text{C}$ and guaranteed by design but not tested in production.

Electrical Characteristics

($T_a = 25^{\circ}\text{C}$)

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{IN}	Operating Input Voltage		2.7		22	V
I_{DD}	Supply Current	$V_{\text{IN}} = 5.5 \text{ V}$, no load, no switching		0.6		mA
		$V_{\text{IN}} = 5.5 \text{ V}$, no load, switching, R1208Kx12A		2.2		mA
		$V_{\text{IN}} = 5.5 \text{ V}$, no load, switching, R1208Kx12B		1.5		mA
I_{standby}	Standby Current	$V_{\text{IN}} = 22 \text{ V}$, $V_{\text{CE}} = 0 \text{ V}$		1.5	10.0	μA
V_{UVLO1}	UVLO Detector Threshold	V_{IN} falling	2.3	2.4		V
V_{UVLO2}	UVLO Released Voltage	V_{IN} rising		$V_{\text{UVLO1}} + 0.1$	2.6	V
V_{CEH}	CE Input Voltage "H"	$V_{\text{IN}} = 22 \text{ V}$	1.5			V
V_{CEL}	CE Input Voltage "L"	$V_{\text{IN}} = 2.7 \text{ V}$			0.4	V
R_{CE}	CE Pull-down Resistance	$V_{\text{IN}} = 8 \text{ V}$		1200		k Ω
V_{S}	V_{S} Active Voltage	$V_{\text{IN}} = 8 \text{ V}$		5		V
I_{LED}	LED1-4 Current Accuracy	$R_{\text{ISET}} = 10 \text{ k}\Omega$, 1 string = 20 mA, $V_{\text{IN}} = 3.6 \text{ V}$,	-3%	20	+3%	mA
$\Delta I_{\text{LED}} / \Delta T_a$	LED1-4 Current Temperature Coefficient	$-40^{\circ}\text{C} \leq T_a \leq 85^{\circ}\text{C}$, $V_{\text{IN}} = 3.6 \text{ V}$		± 100		ppm / $^{\circ}\text{C}$
I_{LEDM}	LED1-4 Current Matching	$(I_{\text{MAX}} - I_{\text{AVE}}) / I_{\text{AVE}}$, 1 string = 20 mA, $V_{\text{IN}} = 3.6 \text{ V}$,			2.5	%
I_{LEDM2}	LED1-4 Current Matching 2	$(I_{\text{MAX}} - I_{\text{AVE}}) / I_{\text{AVE}}$, 1 string = 2 mA			10	%
CEduty	CE Input Duty Range	$V_{\text{IN}} = 3.6 \text{ V}$, $R_{\text{ISET}} = 10 \text{ k}\Omega$	2.3		100	%
I_{LEDMAX}	LED1-4 Max. Current Setting (100% dimming)	$V_{\text{IN}} = 3.6 \text{ V}$	80	100		mA
V_{LED1}	LED1-4 Active Voltage	$V_{\text{IN}} = 3.6 \text{ V}$, 1 string = 30 mA		0.75		V
I_{LEDLEAK}	LED1-4 Leakage Current	$V_{\text{IN}} = V_{\text{LED1-4}} = 22 \text{ V}$, $V_{\text{CE}} = 0 \text{ V}$		0	3.0	μA
R_{ON}	NMOS ON Resistance	$I_{\text{LX}} = 100 \text{ mA}$, $V_{\text{IN}} = 3.6 \text{ V}$		0.28		Ω
I_{LXLEAK}	NMOS Leakage Current	$V_{\text{IN}} = V_{\text{LED1-4}} = 22 \text{ V}$, $V_{\text{CE}} = 0 \text{ V}$		0	3.0	μA
I_{LXLIM}	NMOS Current Limit	$V_{\text{IN}} = 3.6 \text{ V}$	1.5	2	2.5	A
fosc	Oscillator Frequency	$V_{\text{IN}} = 3.6 \text{ V}$ (R1208Kx12A)	675	750	825	kHz
		$V_{\text{IN}} = 3.6 \text{ V}$ (R1208Kx12B)	400	450	500	kHz

ELECTRICAL CHARACTERISTICS (continued)

The specifications surrounded by are over $-40^{\circ}\text{C} \leq T_a \leq 85^{\circ}\text{C}$ and guaranteed by design but not tested in production.

Electrical Characteristics

($T_a = 25^{\circ}\text{C}$)

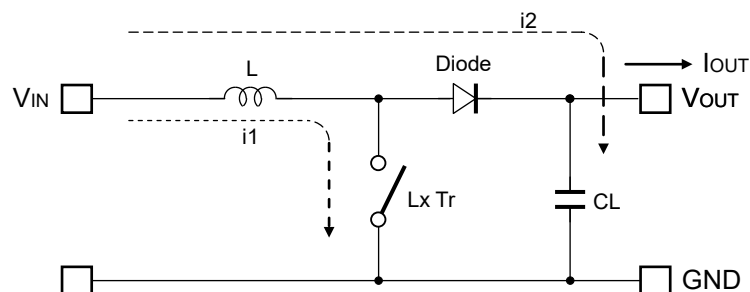
Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
Maxduty	Maximum Duty Cycle	$V_{\text{IN}} = 3.6\text{ V}$		92			%
V_{OVP1}	V_{OUT} OVP Detector Threshold	$V_{\text{IN}} = 3.6\text{ V}$, V_{OUT} rising	R1208K112*	22	23	24	V
			R1208K212*	31.5	33	34.5	V
			R1208K312*	42	43.5	45	V
V_{OVP2}	V_{OUT} OVP Release Voltage	$V_{\text{IN}} = 3.6\text{ V}$, V_{OUT} falling	R1208K112*	21	$V_{\text{OVP1}} - 0.5$		V
			R1208K212*	30.5	$V_{\text{OVP1}} - 1$		V
			R1208K312*	39.5	$V_{\text{OVP1}} - 1.5$		V
V_{OVP3}	LED OVP Detector Threshold	$V_{\text{IN}} = 3.6\text{ V}$, $V_{\text{LED1-4}}$ rising			10	11.5	V
T_{SS}	Soft Start Time	$V_{\text{IN}} = 3.6\text{ V}$		10	15	32	ms
T_{TSD}	Thermal Shutdown Temperature	$V_{\text{IN}} = 3.6\text{ V}$			150		°C
T_{TSR}	Thermal Shutdown Release Temperature	$V_{\text{IN}} = 3.6\text{ V}$			120		°C

All test items listed under *ELECTRICAL CHARACTERISTICS* are done under the pulse load condition ($T_j \approx T_a = 25^{\circ}\text{C}$).

THEORY OF OPERATION

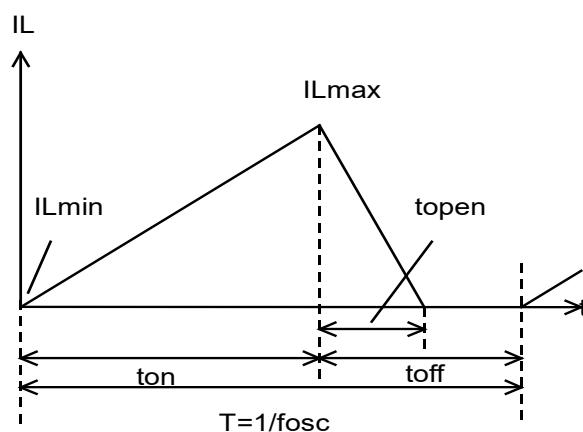
Operation of Step-Up DC/DC Converter and Output Current

<Basic Circuit>

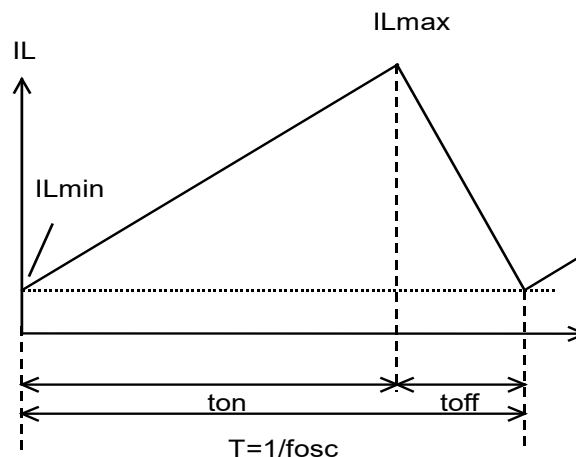


<Current through L>

Discontinuous mode



Continuous mode



There are two operation modes of the step-up PWM control-DC/DC converter. That is the continuous mode and discontinuous mode by the continuousness inductor.

When the transistor turns ON, the voltage of inductor L becomes equal to V_{IN} voltage. The increase value of inductor current ($i1$) will be

$$\Delta i1 = V_{IN} \times t_{on} / L \dots \dots \dots \text{Formula 1}$$

As the step-up circuit, during the OFF time (when the transistor turns OFF) the voltage is continually supply from the power supply. The decrease value of inductor current ($i2$) will be

$$\Delta i2 = (V_{OUT} - V_{IN}) \times t_{open} / L \dots \dots \dots \text{Formula 2}$$

At the PWM control-method, the inductor current become continuously when $t_{open}=t_{off}$, the DC/DC converter operate as the continuous mode.

In the continuous mode, the variation of current of i_1 and i_2 is same at regular condition.

$$V_{IN} \times t_{on} / L = (V_{OUT} - V_{IN}) \times t_{off} / L \dots\dots\dots \text{Formula 3}$$

The duty at continuous mode will be

$$\text{duty (\%)} = t_{on} / (t_{on} + t_{off}) = (V_{OUT} - V_{IN}) / V_{OUT} \dots\dots\dots \text{Formula 4}$$

The average of inductor current at $t_f = t_{off}$ will be

$$I_L(\text{Ave.}) = V_{IN} \times t_{on} / (2 \times L) \dots\dots\dots \text{Formula 5}$$

If the input voltage = output voltage, the I_{OUT} will be

$$I_{OUT} = V_{IN}^2 \times t_{on} / (2 \times L \times V_{OUT}) \dots\dots\dots \text{Formula 6}$$

If the I_{OUT} value is large than above the calculated value (Formula 6), it will become the continuous mode, at this status, the peak current (I_{Lmax}) of inductor will be

$$I_{Lmax} = I_{OUT} \times V_{OUT} / V_{IN} + V_{IN} \times t_{on} / (2 \times L) \dots\dots\dots \text{Formula 7}$$

$$I_{Lmax} = I_{OUT} \times V_{OUT} / V_{IN} + V_{IN} \times T \times (V_{OUT} - V_{IN}) / (2 \times L \times V_{OUT}) \dots\dots\dots \text{Formula 8}$$

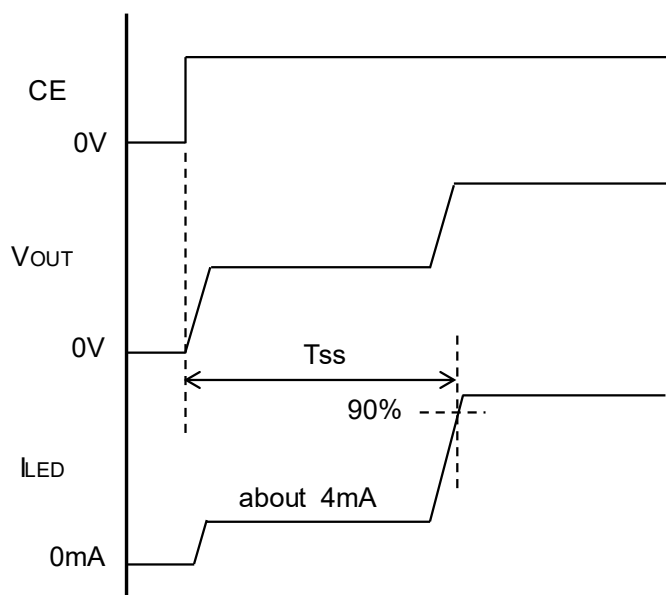
The peak current value is larger than the I_{OUT} value. In case of this, selecting the condition of the input and the output and the external components by considering of I_{Lmax} value.

The explanation above is based on the ideal calculation, and the loss caused by L_x switch and the external components are not included.

The actual maximum output current will be between 50% and 80% by the above calculations. Especially, when the I_L is large or V_{IN} is low, the loss of V_{IN} is generated with on resistance of the switch. Moreover, it is necessary to consider V_f of the diode (approximately 0.8V) about V_{OUT} .

• Soft-Start Function

At startup, by forcibly switching Lx for a certain period of time, V_{OUT} is raised with the LED current flowing about 4mA. During this period, the rush current is suppressed by gradually increasing the current limit. After the time required to raise the V_{OUT} has elapsed, gradually change the LED current from about 4mA to the set current value. The soft start time (T_{ss} = typ.15ms) is the time from CE= "L"→"H" to 90% of the set current for I_{LED} .



• Current Limit Function

If the peak current of inductor (I_{Lmax}) exceeds the current limit, current limit function turns the driver off and turns it on in every switching cycle to continually monitor the driver current.

• Under Voltage Lockout (UVLO) Function

UVLO function stops DC/DC operation to prevent malfunction when the supply voltage falls below the UVLO detector threshold.

• Overvoltage Protection (OVP) Circuit

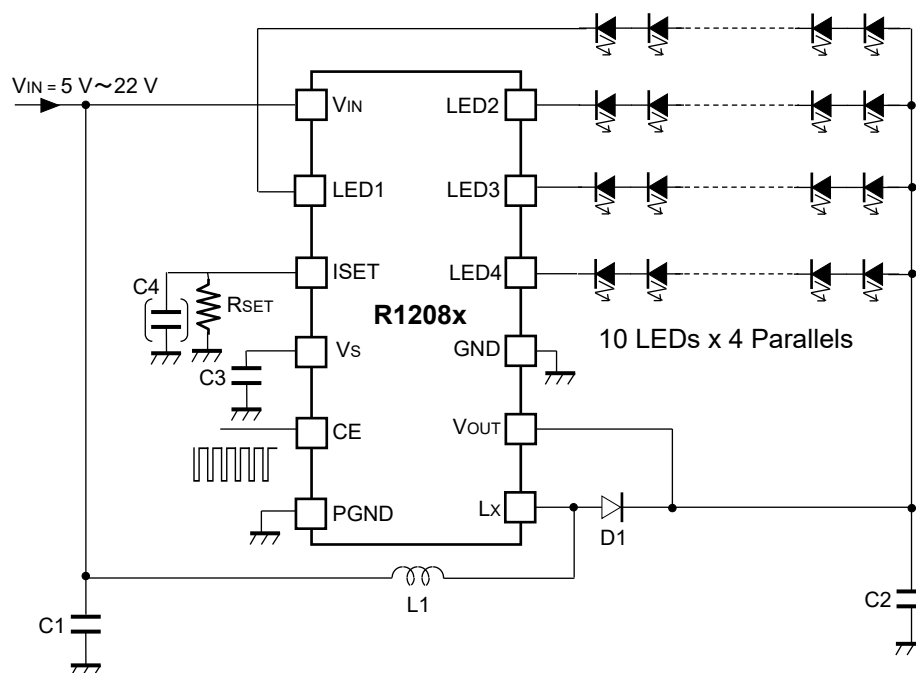
OVP circuit monitors the V_{OUT} pin voltage and halts oscillation once it reaches the OVP detect voltage. Oscillation resumes when the V_{OUT} pin voltage decreases below 0.3 V. In case the cause of the excess V_{OUT} pin voltage is not removed the OVP circuit will stop and resume repeatedly in order to limit the V_{OUT} pin voltage.

• Thermal Shutdown Function

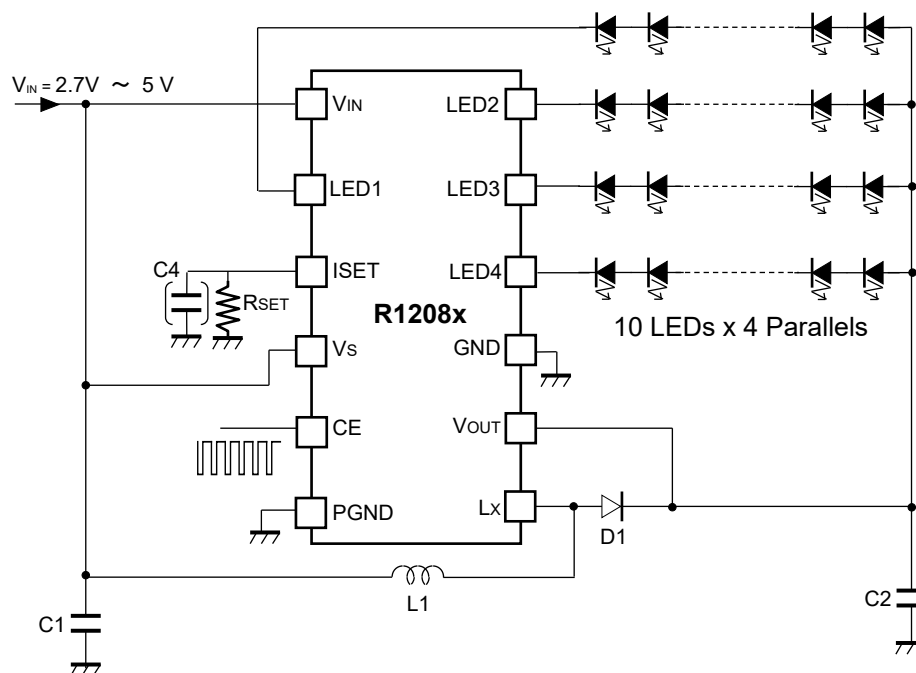
Thermal shutdown circuit detects overheating of the converter if the output pin is shorted to the ground pin (GND) etc. and stops the converter operation to protect it from damage. If the junction temperature of the device exceeds the specified temperature, the thermal shutdown stops the converter operation and resumes the converter operation if the junction temperature decreases below the thermal shutdown release temperature.

APPLICATION INFORMATION

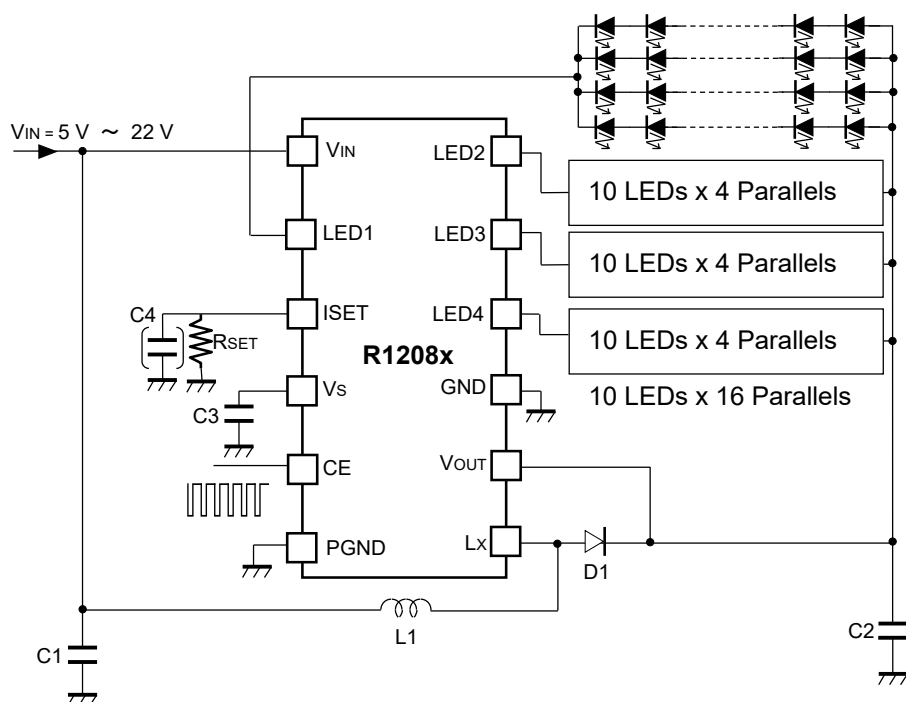
Typical Applications



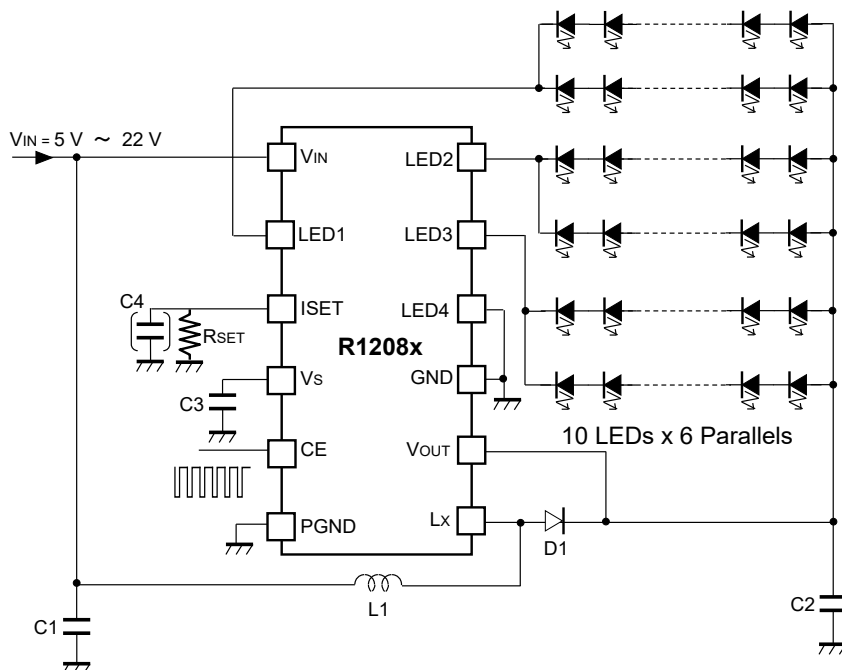
Typical Application 1. 10 LEDs in series x 4 parallels, up to 80 mA per LED, 5 V or higher power supply voltage, using 4 LED channels



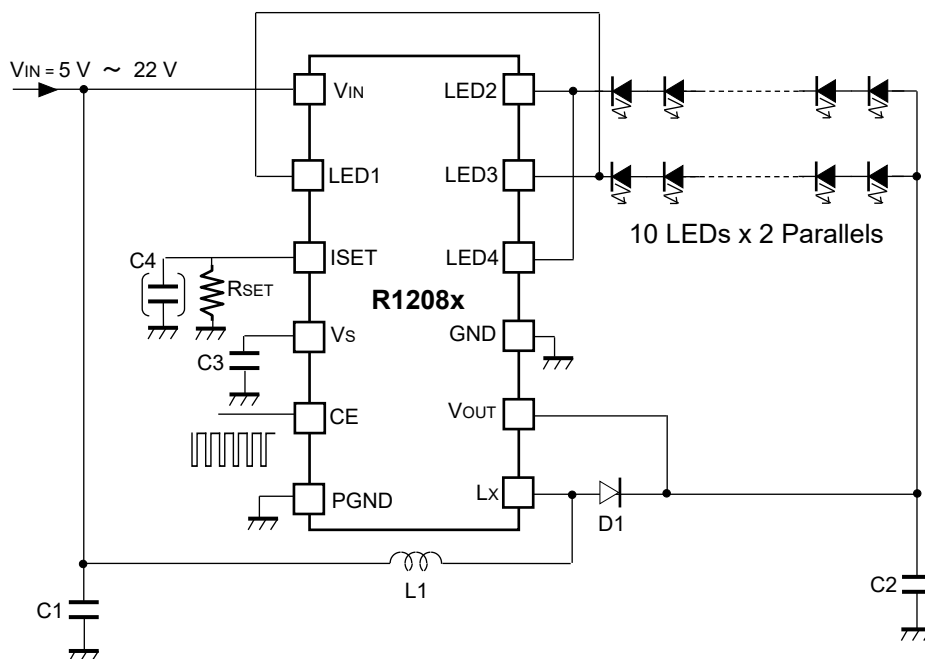
Typical Application 2. 10 LEDs in series x 4 parallels, up to 80 mA per LED, less than 5 V power supply voltage, using 4 LED channels



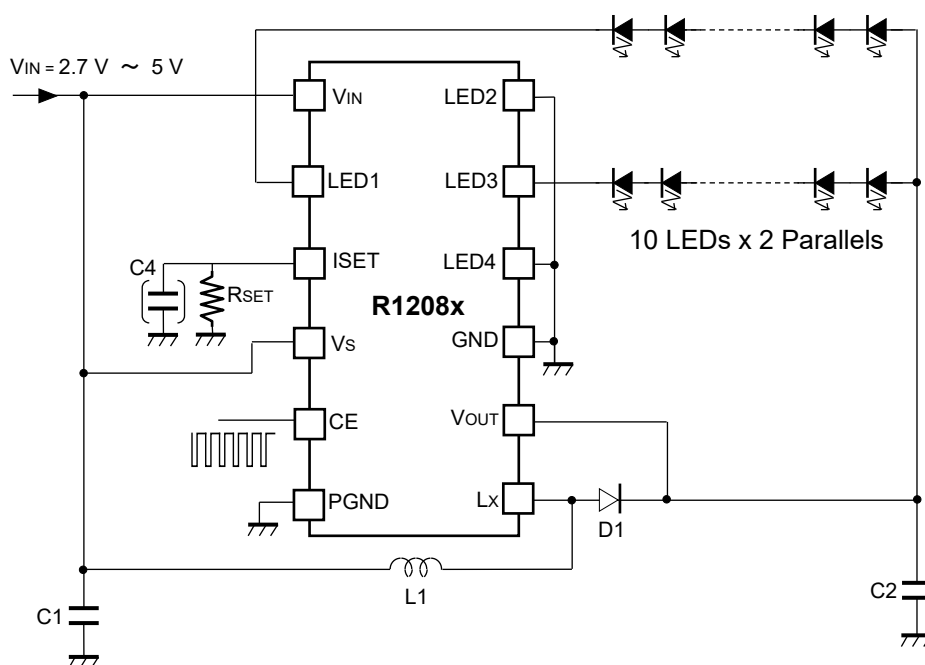
**Typical Application 3. 10 LEDs in series x 16 parallels, up to 20 mA per LED,
5 V or higher power supply voltage, using 4 LED channels**



**Typical Application 4. 10 LEDs in series x 6 parallels, up to 40 mA per LED,
5 V or higher power supply voltage, using 3 LED channels**



Typical Application 5. 10 LEDs in series x 2 parallels, up to 160 mA per LED, 5 V or higher power supply voltage, using 4 LED channels



Typical Application 6. 10 LEDs in series x 2 parallels, up to 80 mA per LED, less than 5 V power supply voltage, using 2 LED channels

Recommended Inductors

Frequency (kHz)	L1 (μH)	Parts No.	Rated Current (mA)	Size (mm)
750	10	VLS252010ET-100M	550	2.5 × 2.0 × 1.0
		VLF302512MT-100M	620	3.0 × 2.5 × 1.2
		VLF403212MT-100M	900	4.0 × 3.2 × 1.2
		VLF504012MT-100M	1320	5.0 × 4.0 × 1.2
450	22	VLF302512MT-220M	430	3.0 × 2.5 × 1.2
		VLF403212MT-220M	540	4.0 × 3.2 × 1.2
		VLF504012MT-220M	890	5.0 × 4.0 × 1.2
		VLS5045EX-220M	1800	5.0 × 5.0 × 4.5

Recommended Components

Symbol	Rated Voltage (V)	Parts No.
D1	60	CRS12
	60	RB060M-60
C1	25	C3225JB1E475M
C2	50	C2012X5R1H225K C2012X5R1H105K ^{*1}
C3	25	C1608X5R1E224M
C4	6.3	CM105B105K06

^{*1} When I_{LED} = 80 mA or lower at 750 kHz

- Selection of Inductor**

Peak current of inductor (I_{Lmax}) in normal mode when the efficiency is 80% can be calculated by the following formula.

$$I_{Lmax} = 1.25 \times I_{OUT} \times V_{OUT} / V_{IN} + 0.5 \times V_{IN} \times (V_{OUT} - V_{IN}) / (L1 \times V_{OUT} \times f_{osc})$$

When starting up the IC or when adjusting the brightness of LEDs, a large transient current may flow into an inductor (L1). I_{Lmax} should be equal or smaller than the current limit of the IC. When deciding the rated current of inductor, I_{Lmax} should be considered. It is recommended that L1 with 10 μH to 22 μH be used.

- Selection of Capacitor**

Set a 1 μF or more input capacitor (C1) between the V_{IN} and GND pins as close as possible to the pins.

Set a 1 μF output capacitor (C2) between the V_{OUT} and GND pins if I_{LED} ≤ 80 mA and an inductor is 10 μH.

In other cases, set a 2.2 μF or more output capacitor (C2) between the V_{OUT} and GND pins.

• Selection of Diode

For a rectifier diode, use a schottky barrier diode that has low V_F .

It is recommended to select a schottky barrier diode that has low reverse current and low parasitic capacitance.

• VS Pin Connection at $V_{IN} < 5\text{ V}$

When using the VS pin at $V_{IN} < 5\text{ V}$, it is recommended that the V_{IN} pin and the VS pin be short-circuited each other. Refer to *Typical Application 2* and 6. There's no capacitor required between the VS pin and the GND pin.

If the V_{IN} pin and the VS pin are not shorted each other, a capacitor (C3) is required between the VS pin and the GND pin. Refer to *Typical Application 1, 3, 4, and 5*.

• LED Current Setting

The LED current (I_{LEDSET}) when a "H" PWM signal is applied to the CE pin (Duty = 100%) can be determined by the value of feedback resistor (R_{SET}). If a 10 k Ω resistor (R_{SET}) is placed between the ISET pin and the GND pin, the LED pin current will be set to 20 mA.

$$I_{LEDSET} = 0.103 \times R_{SET} / (41.5\text{ k} + R_{SET})$$

Choose 4.4 k Ω (10 mA) to 143 k Ω (80 mA) for R_{SET} .

By using the application example of *Typical Application 5*, the LED current can be set between 80 mA to 160 mA.

The LED current can be set up to 320 mA by using the four LED pins.

• LED Dimming Control

The brightness of the LEDs can be adjusted by applying a PWM signal to the CE pin. If the High-Duty of PWM input of the CE is Hduty, the current of LED can be calculated by the following formula.

$$I_{LED} = Hduty \times I_{LEDSET}$$

The minimum High-duty of a PWM signal can be controlled up to 2.3% ($T_a = 25^\circ\text{C}$).

However, the I_{LED} current is controlled to approximately 4mA during the soft start time.

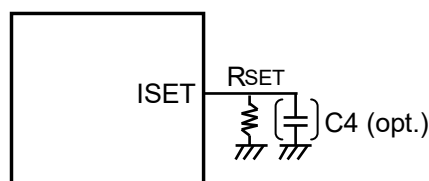
By inputting "L" voltage for a certain period of time (Typ. 12 ms for R1208KxxxA/ 18 ms for R1208KxxxB), the IC goes into standby mode and turns off LEDs.

• PWM Dimming Adjustment Frequency

The frequency range of a PWM signal should be set within the range of 200 Hz to 300 kHz.

In the case of using a 20 kHz or less PWM signal for dimming the LEDs, the increasing or decreasing of the inductor current (IL) may generate noise in the audible band. In this case, connect a capacitor (C4) between the ISET pin and GND pin.

In the case of using a 20 kHz or more PWM signal, connecting a capacitor is not required. Refer to *Typical Application 2*, *Typical Application 5* and *Typical Application 6* for details.



• Unused LED Current Source

Unused LED pin should be connected to GND. When using two or three LED pins, it is recommended that the rest of the LED pins should be connected as below.

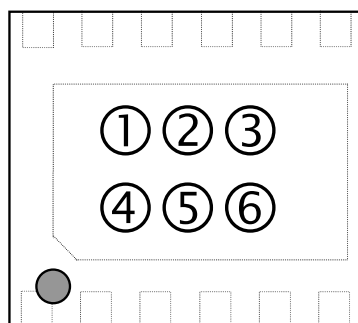
Using two LED pins: LED 2 and LED 4 should be connected to GND. Refer to *Typical Application 6*.

Using three LED pins: LED 4 should be connected to GND. Refer to *Typical Application 4*.

Mark Specification (DFN(PL)2730-12)

①②③④: Product Code ... Refer to MARK SPECIFICATION TABLE (DFN(PL)2730-12)

⑤⑥: Lot Number ... Alphanumeric Serial Number



DFN(PL)2730-12 Mark Specification

NOTICE

There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact our sales or our distributor before attempting to use AOI.

Mark Specification Table (DFN(PL)2730-12)

R1208x Mark Specification Table

Product Name	①②③④
R1208K112A	D Y 0 0
R1208K212A	D Y 0 1
R1208K312A	D Y 0 2
R1208K112B	D Y 0 3
R1208K212B	D Y 0 4
R1208K312B	D Y 0 5

TECHNICAL NOTES

● Current Path on PCB

Figure 1 and Figure 2 show flows of current paths of the application circuits when MOSFET is ON and when MOSFET is OFF, respectively. Parasitic elements (impedance, inductance or capacitance) in the paths pointed with red arrows in Figure 1 and Figure 2 influence stability of the system and cause noise outbreak. It is recommended that these parasitic elements be minimized. In addition, except for the paths of LED load, it is recommended that the all wirings of the current paths be made as short and wide as possible.

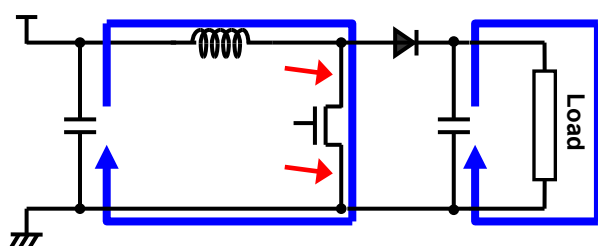


Figure 1. MOSFET-ON

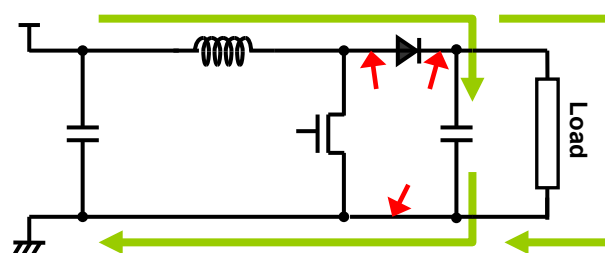
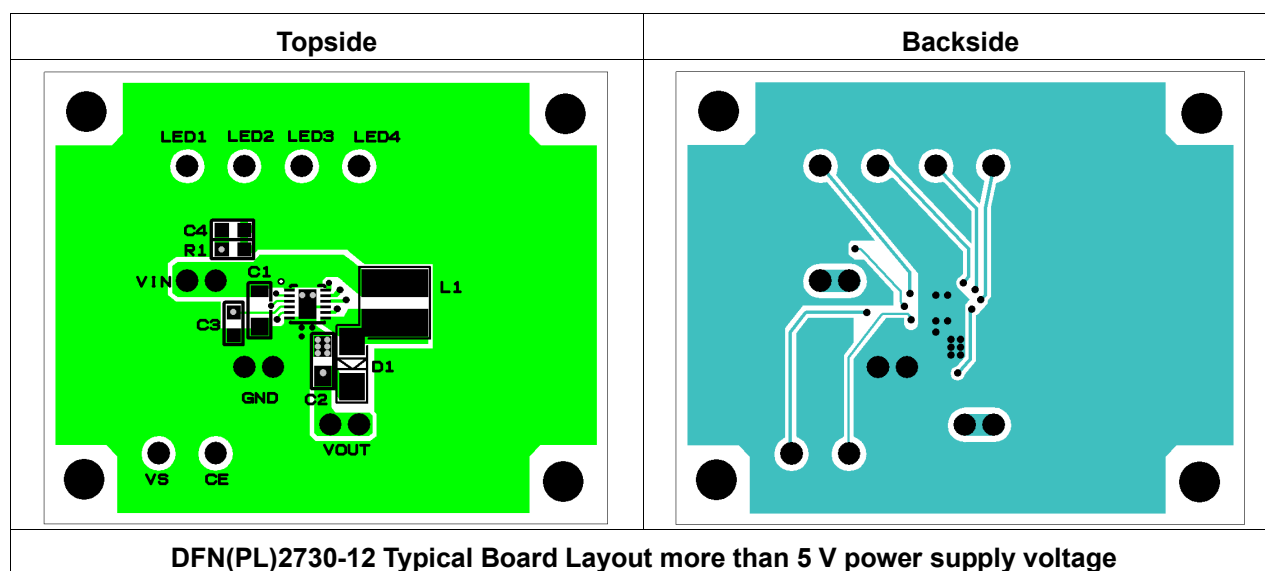
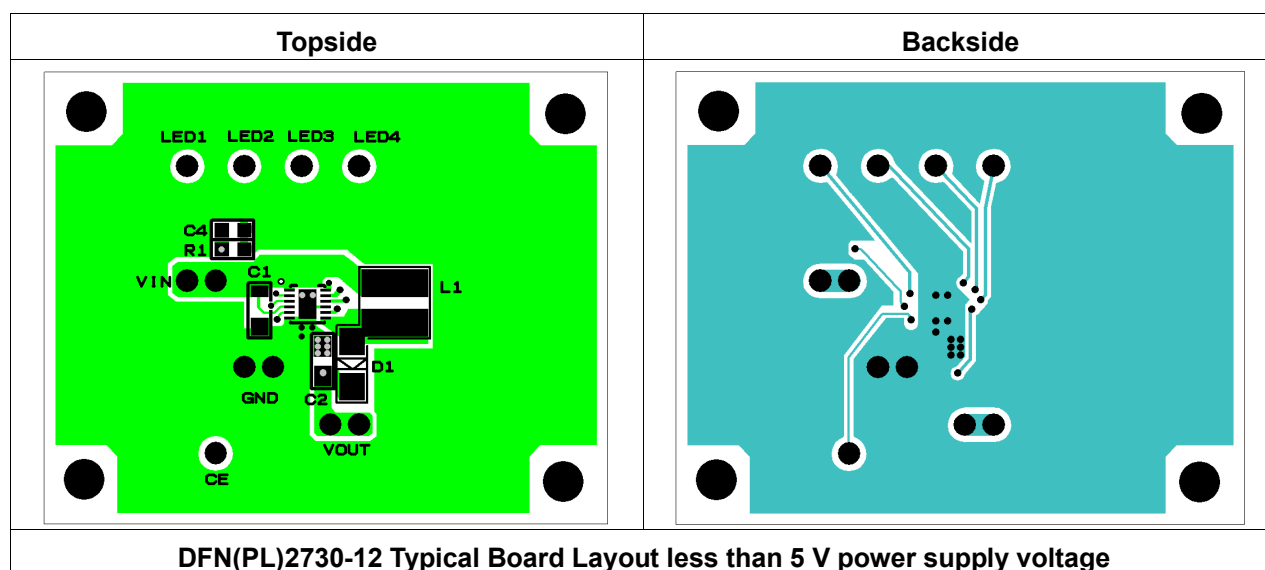


Figure 2. MOSFET-OFF

● Layout Guide for PCB

- Place C1 as close as possible to the V_{IN} and GND pins. Also, connect the GND pin to the wider GND plane.
- Make the L_X land pattern as small as possible.
- Make the wirings between the L_X pin, the inductor and the diode as short as possible. Also, connect C2 as close as possible to the cathode of the diode.
- Place C2 as close as possible to the GND pin.

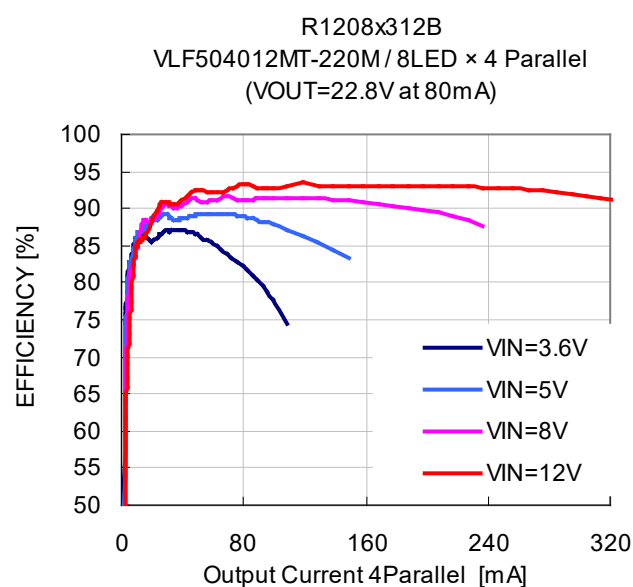
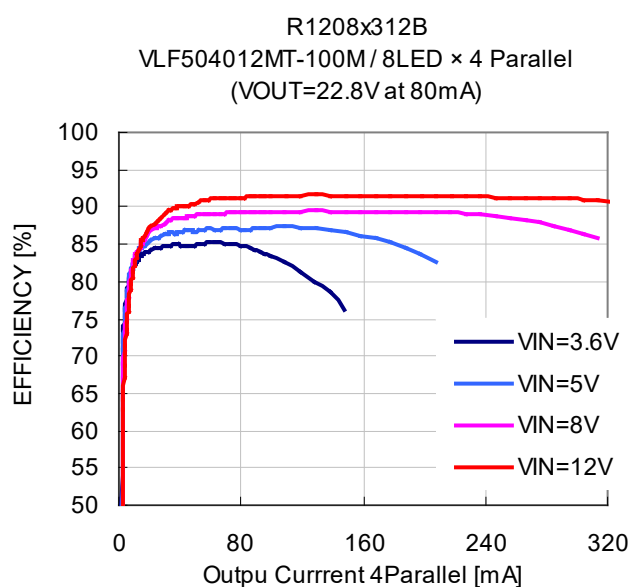
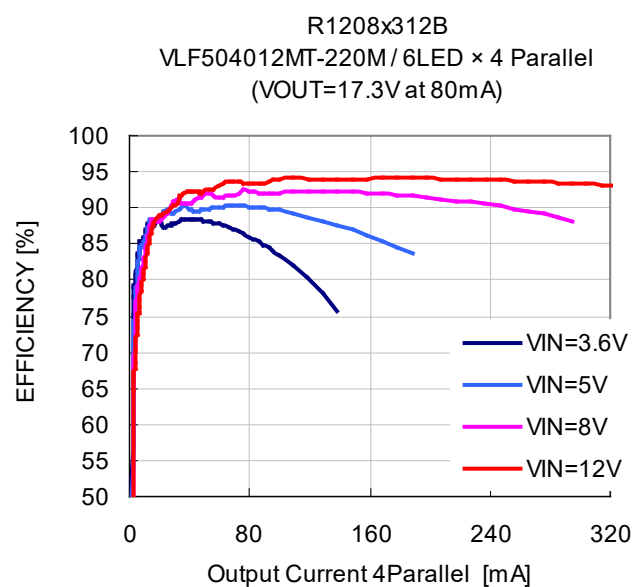
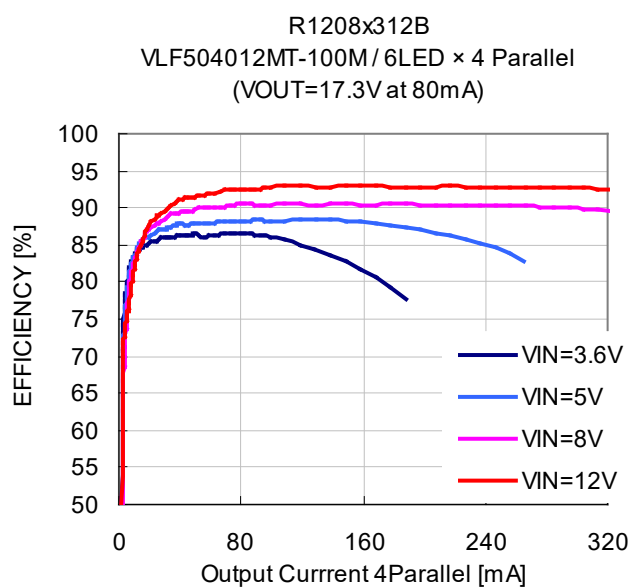
- PCB Layout



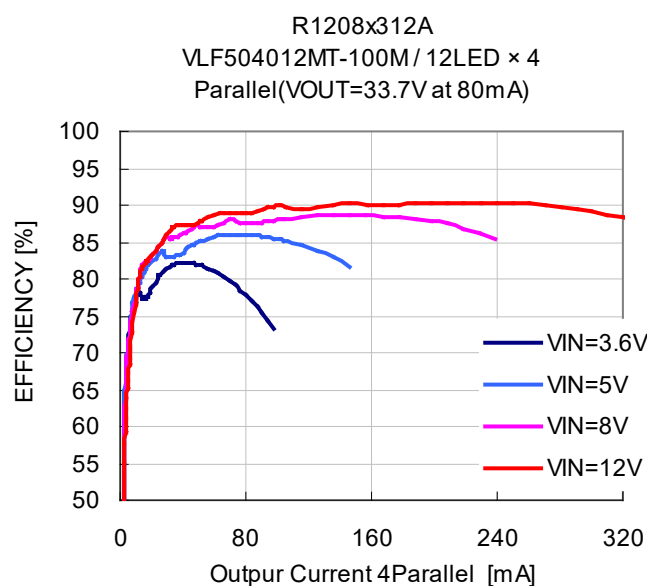
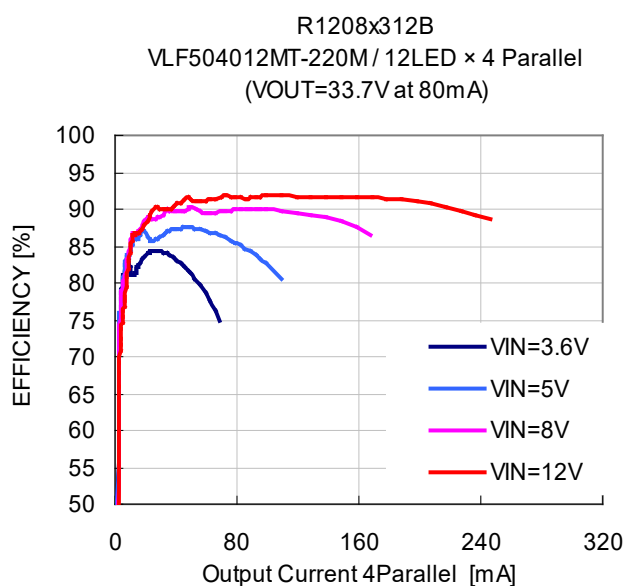
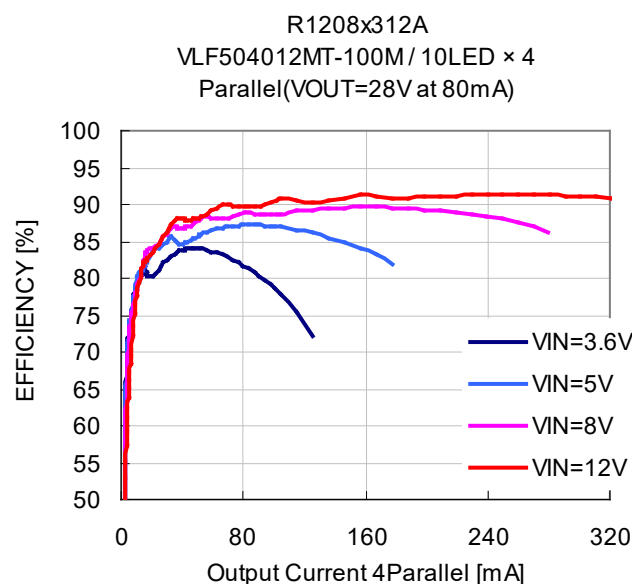
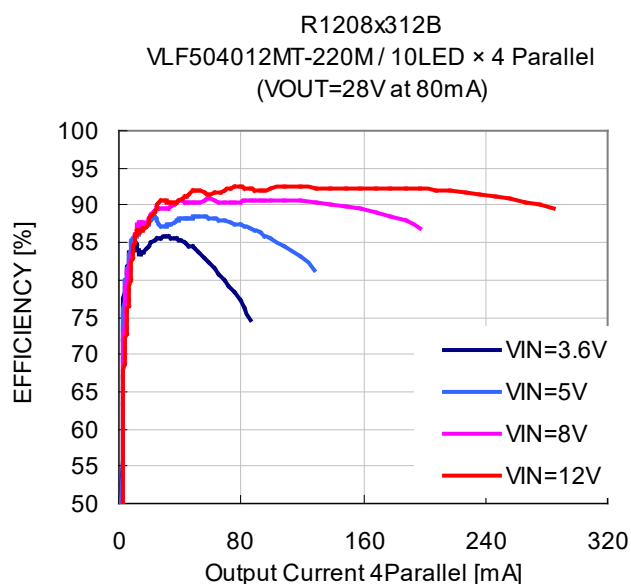
TYPICAL CHARACTERISTICS

1) Efficiency vs. Output Current of R1208xx12A/B

1-1) Efficiency vs. Output Current with Different Input Voltages

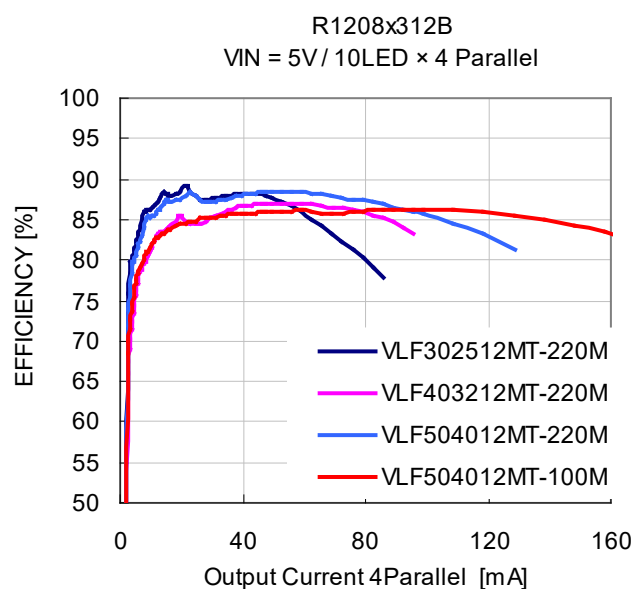
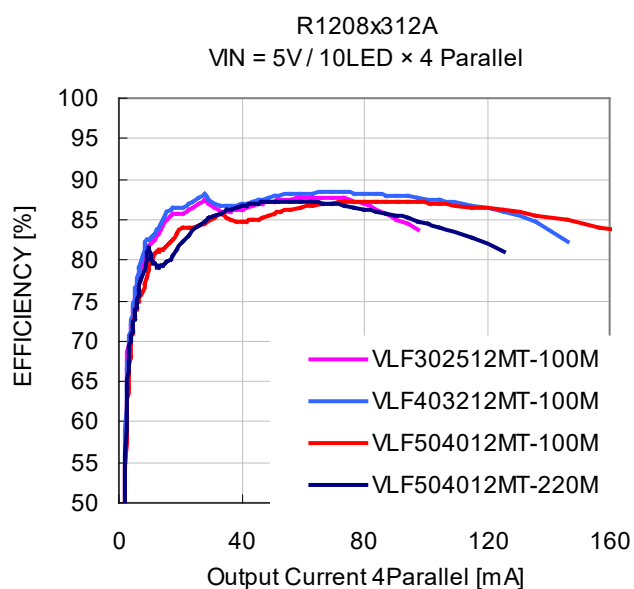
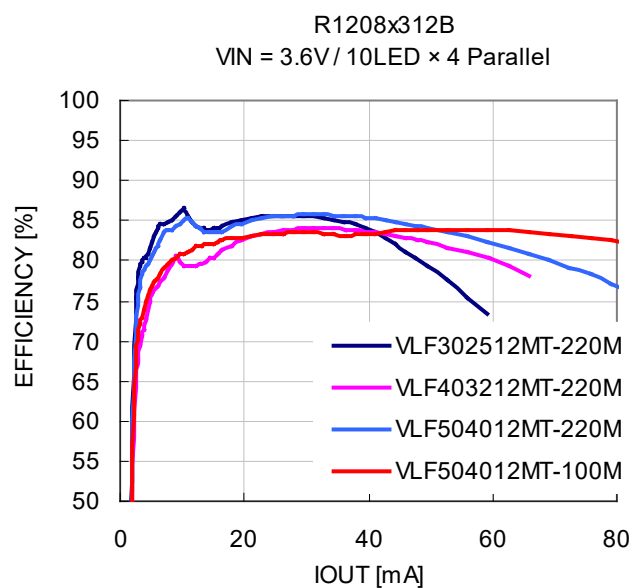
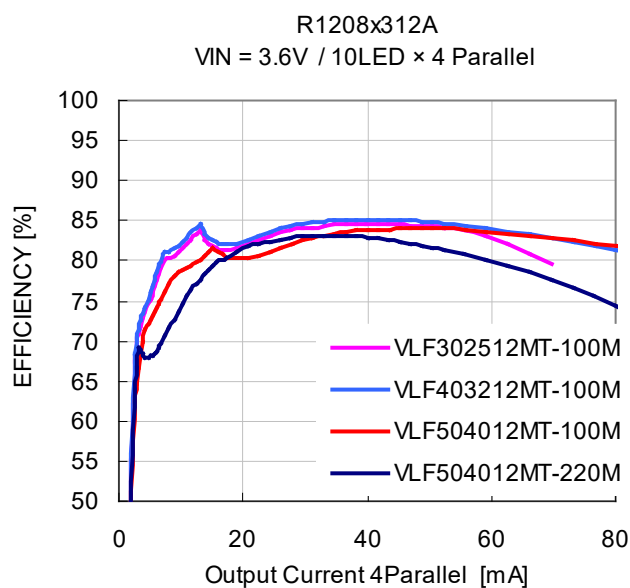


TYPICAL CHARACTERISTICS (continued)

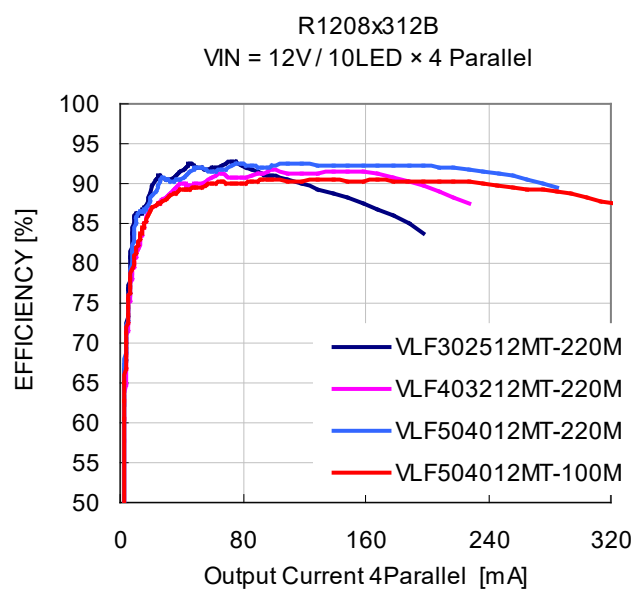
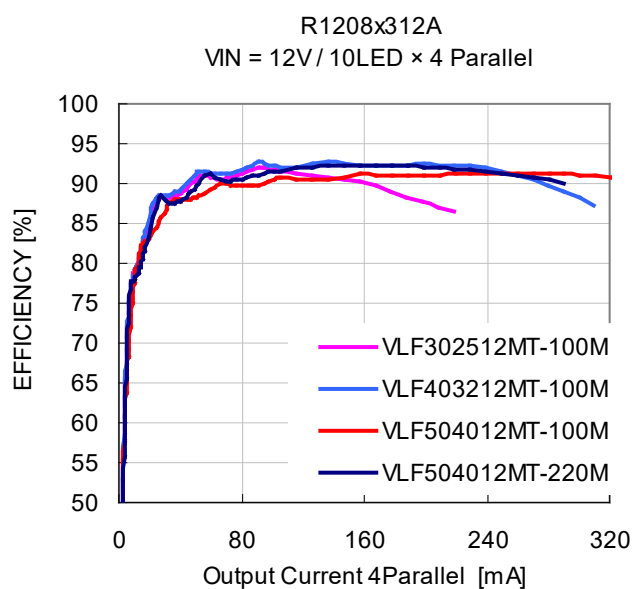
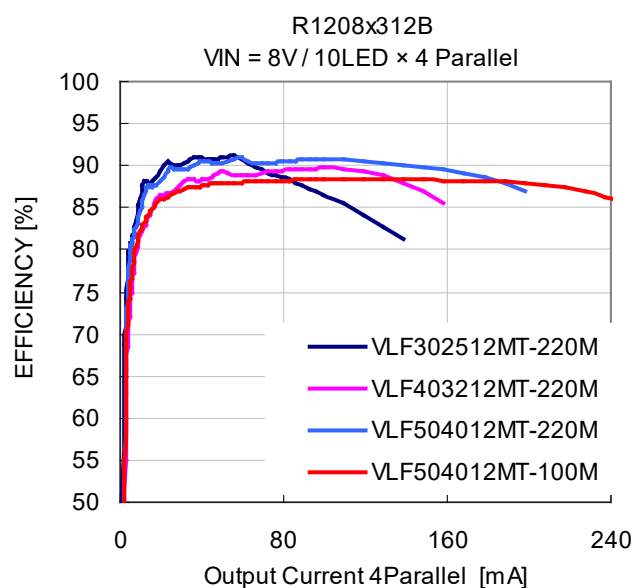
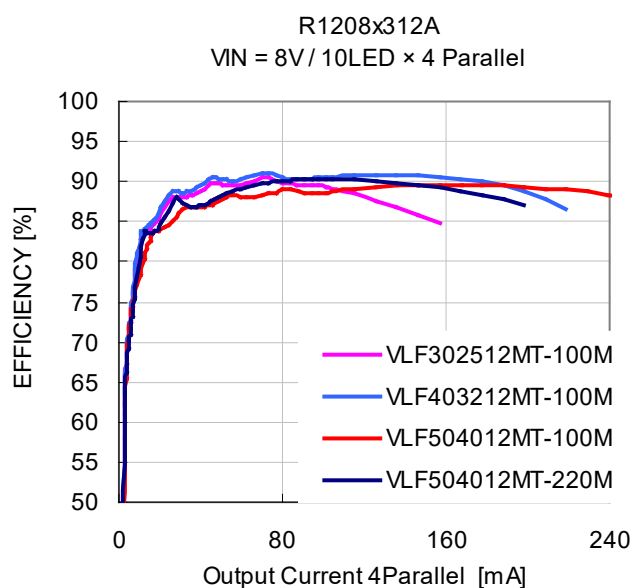


TYPICAL CHARACTERISTICS (continued)

1-2) Efficiency vs. Output Current with Different Inductors ($V_{OUT} = 28\text{ V}$ at 80 mA)

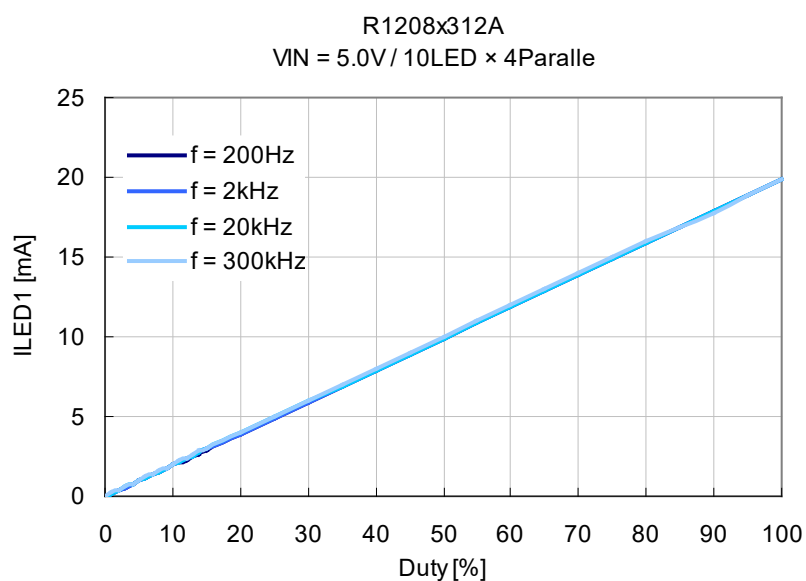


TYPICAL CHARACTERISTICS (continued)



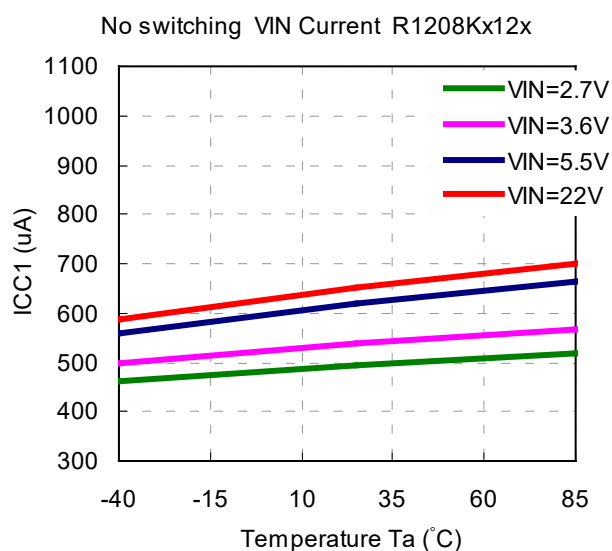
TYPICAL CHARACTERISTICS (continued)

2) Onduty vs. I_{LED} ($I_{SET} = 10\text{ k}\Omega$)



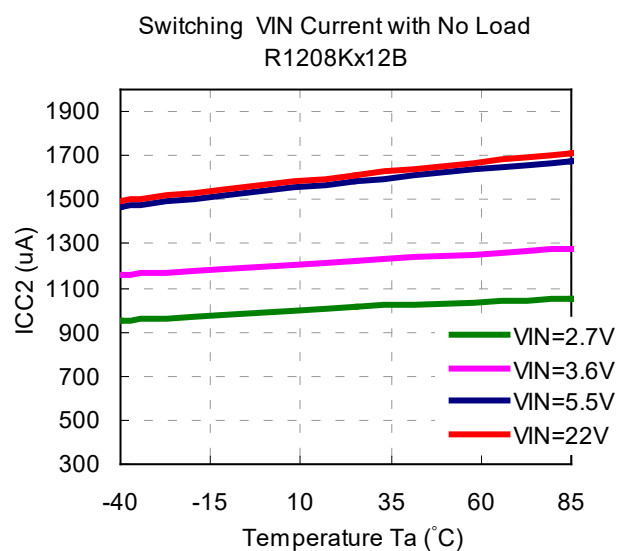
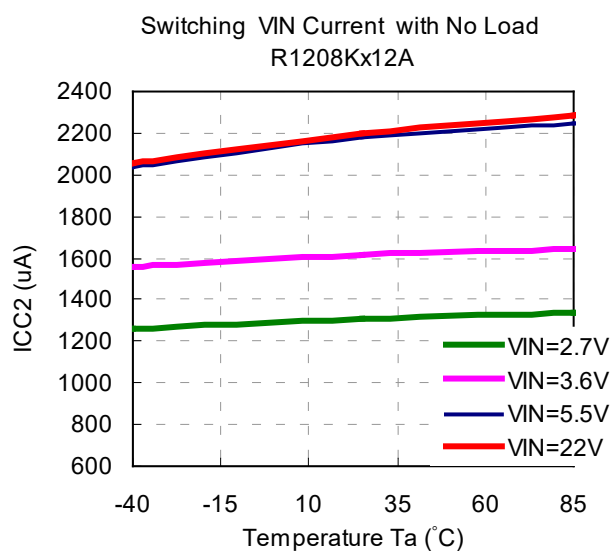
3) Electrical Characteristics

3-1) Supply Current (No switching) vs. Ambient Temperature

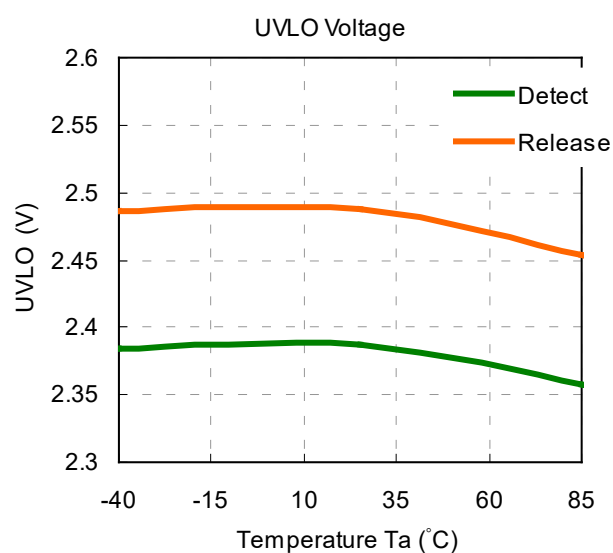


TYPICAL CHARACTERISTICS (continued)

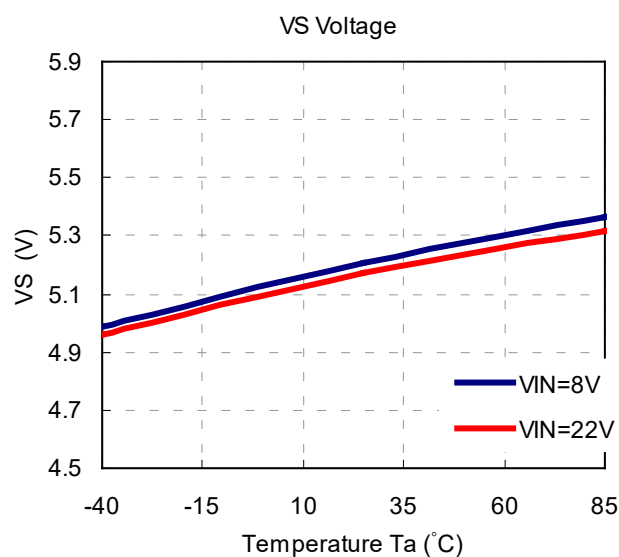
3-2) Supply Current (Switching) vs. Ambient Temperature



3-3) UVLO Voltage vs. Ambient Temperature

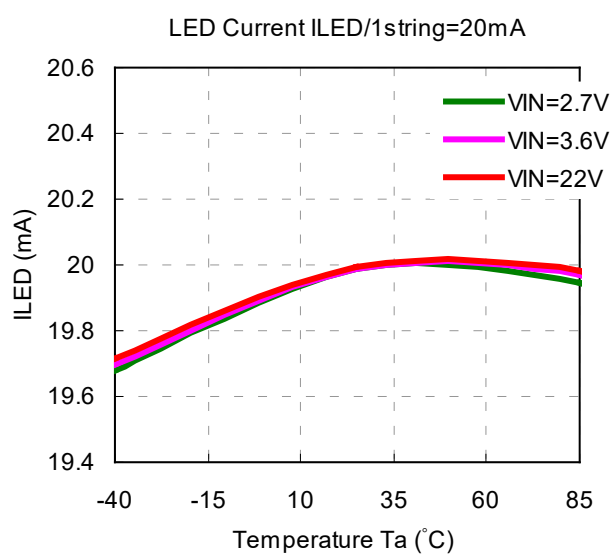


3-4) VS Voltage vs. Ambient Temperature

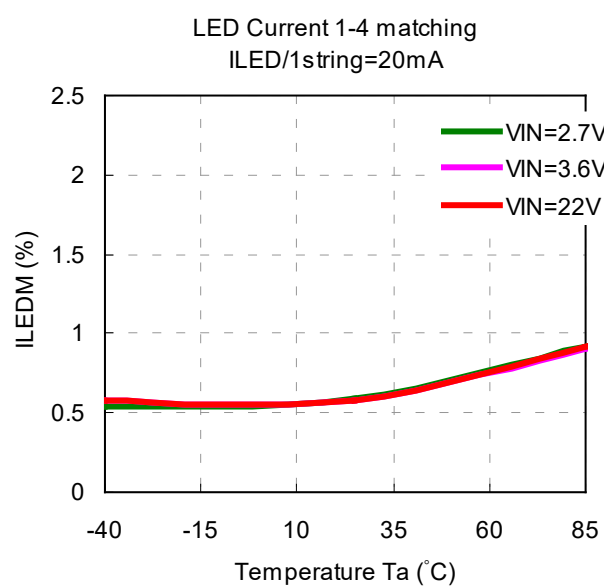


TYPICAL CHARACTERISTICS (continued)

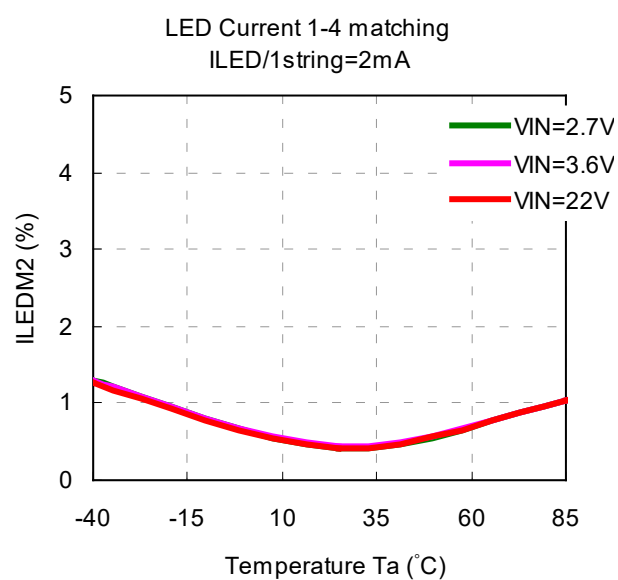
3-5) LED Current Accuracy vs. Ambient Temperature



3-6) Channel Matching vs. Ambient Temperature 1 String: 20 mA

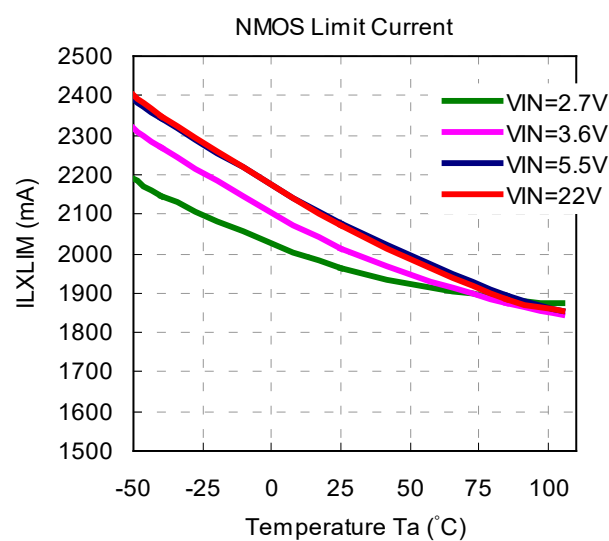
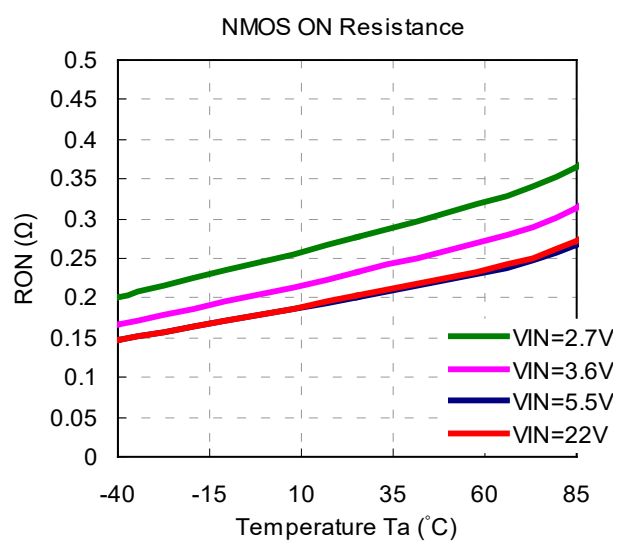


3-7) Channel Matching vs. Ambient Temperature 1 String: 2 mA

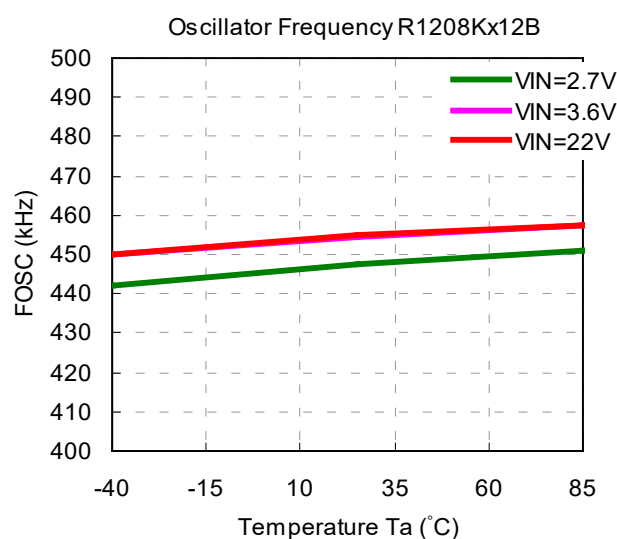
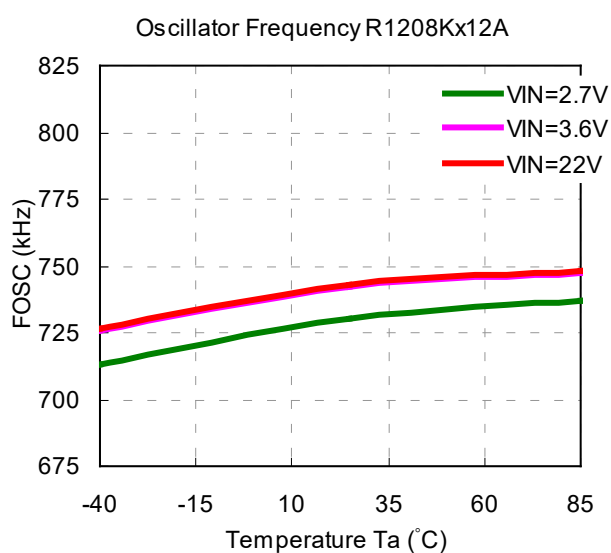


TYPICAL CHARACTERISTICS (continued)

3-8) NMOS ON Resistance vs. Ambient Temperature 3-9) NMOS Limit Current vs. Ambient Temperature

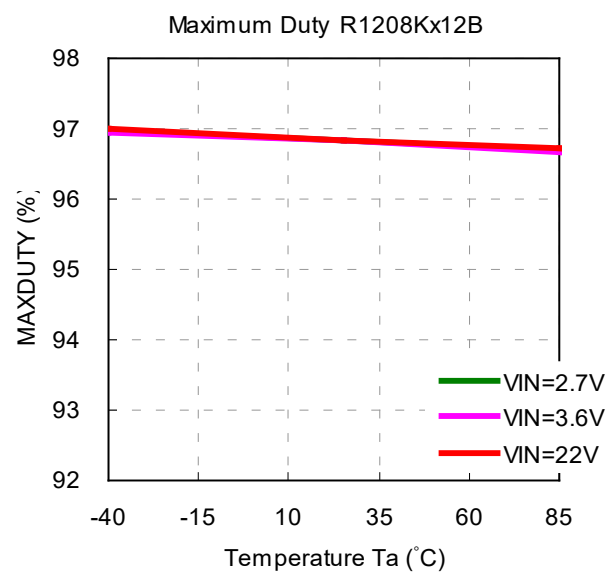
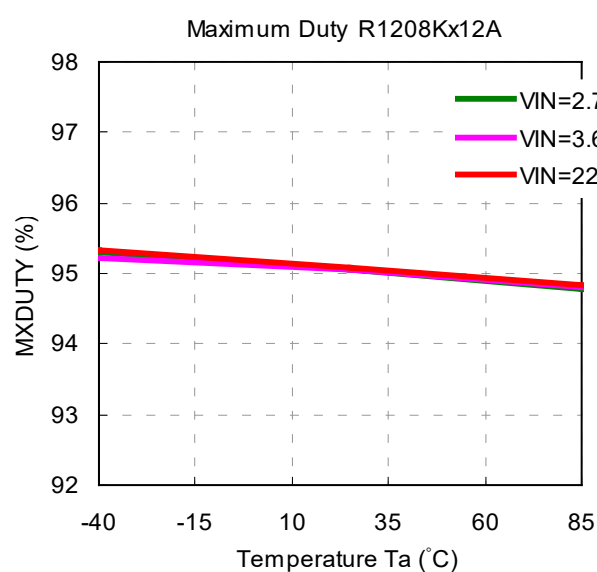


3-10) Operating Frequency vs. Ambient Temperature

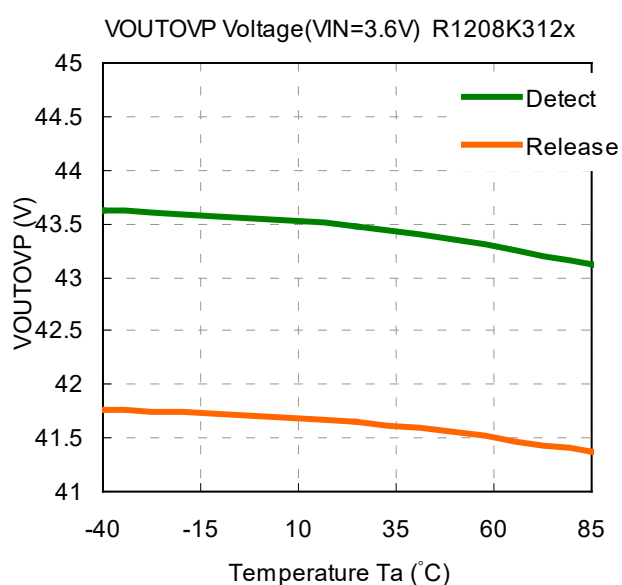


TYPICAL CHARACTERISTICS (continued)

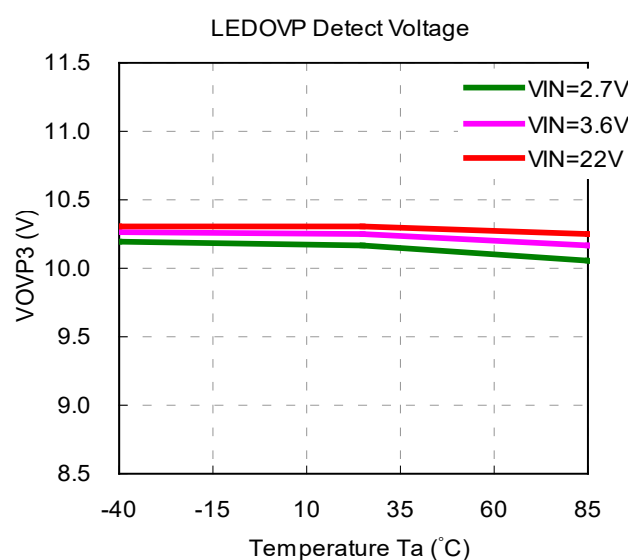
3-11) Maxduty vs. Ambient Temperature



3-12) V_{OUT} OVP Detector Threshold vs. Ambient Temperature

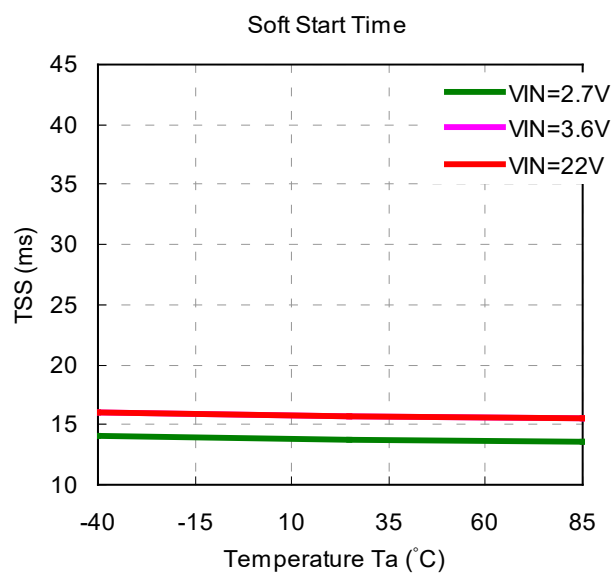


3-13) LED OVP Detector Threshold vs. Ambient Temperature



TYPICAL CHARACTERISTICS (continued)

3-14) Soft-start Time vs. Ambient Temperature



The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51.

Measurement Conditions

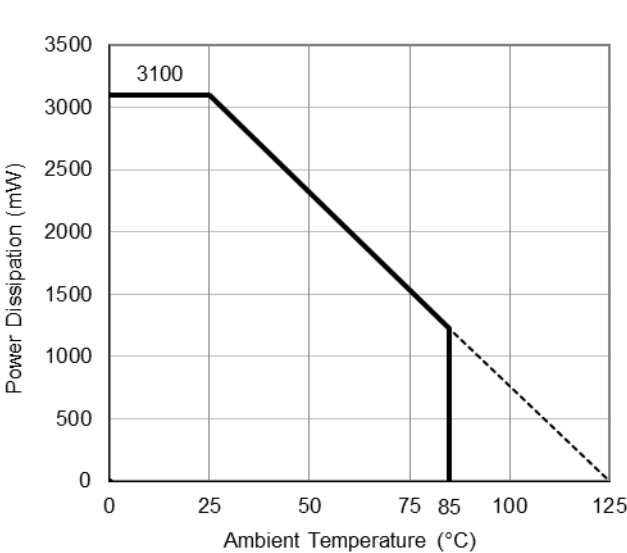
Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 32 pcs

Measurement Result

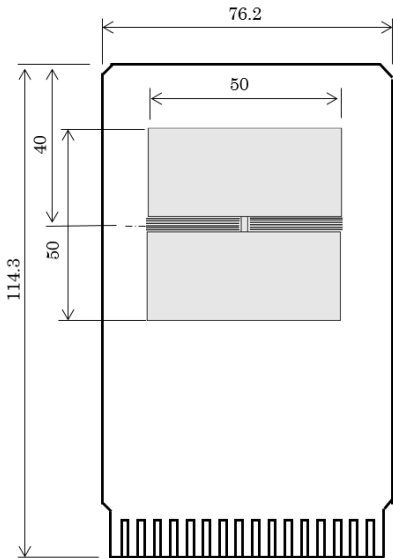
(Ta = 25°C, TJmax = 125°C)

Item	Measurement Result
Power Dissipation	3100 mW
Thermal Resistance (θja)	θja = 32°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 8°C/W

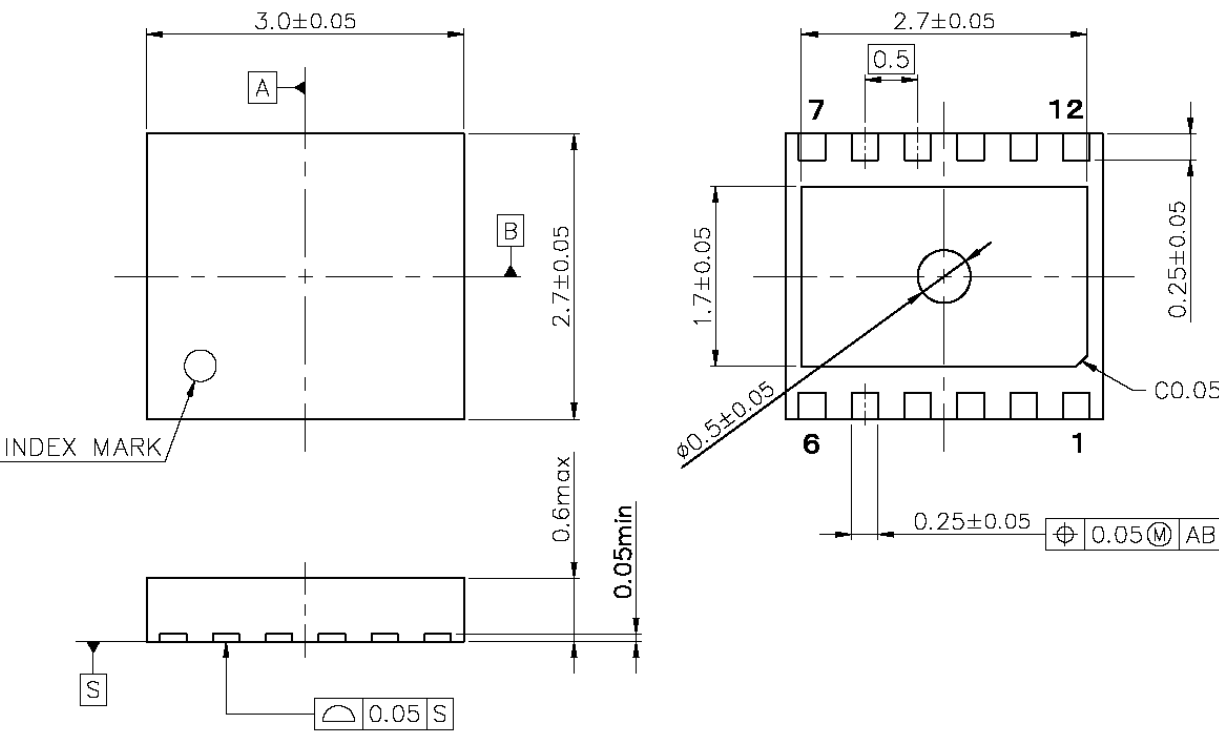
θja: Junction-to-Ambient Thermal Resistance
ψjt: Junction-to-Top Thermal Characterization Parameter



Power Dissipation vs. Ambient Temperature



Measurement Board Pattern



DFN(PL)2730-12 Package Dimensions (Unit: mm)

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 - Combustion equipment

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 - 8-1. **Quality Warranty Period**
In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.
 - 8-2. **Quality Warranty Remedies**
When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.
Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
 - 8-3. **Remedies after Quality Warranty Period**
With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.
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10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
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13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



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